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Technical
Support 2N4416-A

## 2N4416, 2N4416A N-Channel JFET

## Features

- InterFET N0026S Geometry
- Low Noise: $4 \mathrm{nV} / \mathrm{VHz}$ Typical
- Low Leakage: 10pA Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.


## Applications

- Mixers
- VHF Amplifiers


## Description

The -30V InterFET 2N4416 and 2N4416A are targeted for sensitive mixer and VHF Amplifier amplifier designs. Gate leakages are typically less than 10pA at room temperatures. The " $A$ " variant has a higher breakdown Voltage. The TO-72 package is hermetically sealed and suitable for military applications.


SOT23 Top View


TO-92 Bottom View


Product Summary

| Parameters |  | 2N4416 Min | 2N4416A Min | Unit |
| :---: | :---: | :---: | :---: | :---: |
| BVGSS | Gate to Source Breakdown Voltage | -30 | -35 | V |
| Idss | Drain to Source Saturation Current | 5 | 5 | mA |
| $\mathrm{V}_{\text {GS (off) }}$ | Gate to Source Cutoff Voltage |  | -2.5 | V |
| GFs | Forward Transconductance | 4500 | 4500 | $\mu \mathrm{S}$ |

Ordering Information Custom Part and Binning Options Available

| Part Number | Description | Case | Packaging |
| :--- | :--- | :---: | :---: |
| 2N4416; 2N4416A | Through-Hole | TO-72 | Bulk |
| PN4416; PN4416A | Through-Hole | TO-92 | Bulk |
| SMP4416; SMP4416A | Surface Mount | SOT23 | Bulk |
|  | " Tape and Reel: Max 3,000 Pieces <br> 13" Tape and Reel: Max 9,000 Pieces | SOT23 | Minimum 1,000 Pieces <br> Tape and Reel |
| 2N4416COT; 2N4416ACOT | Chip Orientated Tray (COT Waffle Pack) | COT | 400/Waffle Pack |
| 2N4416CFT; 2N4416ACFT | Chip Face-up Tray (CFT Waffle Pack) | CFT | 400/Waffle Pack |

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## Electrical Characteristics

Maximum Ratings (@ $T_{A}=25^{\circ} \mathrm{C}$, Unless otherwise specified, Highlighted values = A variant)

| Parameters | Value | Unit |  |
| :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RGS }}$ | Reverse Gate Source and Gate Drain Voltage |  | V |
|  | -35 | 10 |  |
| $\mathrm{I}_{\text {FG }}$ | Continuous Forward Gate Current | 300 | mW |
| $\mathrm{P}_{\mathrm{D}}$ | Continuous Device Power Dissipation | 2 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| P | Power Derating | -55 to 125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Operating Junction Temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature |  |  |

Static Characteristics (@TA $=25^{\circ} \mathrm{C}$, Unless otherwise specified)

| Parameters |  | Conditions | 2N4416 |  | 2N4416A |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| $V_{\text {(BR) }}$ GSS | Gate to Source Breakdown Voltage |  | $V_{D S}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{G}}=-1 \mu \mathrm{~A}$ | -30 |  | -35 |  | V |
| Igss | Gate to Source Reverse Current | $\begin{gathered} V_{G S}=-20 \mathrm{~V}, V_{D S}=0 V, T_{A}=25^{\circ} \mathrm{C} \\ V_{G S}=-20 \mathrm{~V}, V_{D S}=0 V, T_{A}=150^{\circ} \mathrm{C} \end{gathered}$ |  | $\begin{aligned} & \hline-0.1 \\ & -0.1 \end{aligned}$ |  | $\begin{aligned} & \hline-0.1 \\ & -0.1 \end{aligned}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ |
| VGS(OfF) | Gate to Source Cutoff Voltage | $V_{D S}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{nA}$ |  | -6 | -2.5 | -6 | V |
| loss | Drain to Source Saturation Current | $\begin{gathered} \mathrm{V}_{G S}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V} \\ \text { (Pulsed) } \end{gathered}$ | 5 | 15 | 5 | 15 | mA |

Dynamic Characteristics (@ TA $=25^{\circ} \mathrm{C}$, Unless otherwise specified)

| Parameters |  | Conditions | 2N4416 |  | 2N4416A |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |  |
| Gfs | Forward Transconductance |  | $\begin{gathered} V_{D S}=15 \mathrm{~V}, \mathrm{~V}_{G S}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{kHz} \\ \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{G S}=0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz} \end{gathered}$ | $\begin{aligned} & 4500 \\ & 4000 \end{aligned}$ | 7500 | $\begin{aligned} & 4500 \\ & 4000 \end{aligned}$ | 7500 | $\mu \mathrm{S}$ |
| Gos | Output Conductance | $\mathrm{V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{kHz}$ |  | 50 |  | 50 | $\mu \mathrm{S}$ |
|  |  | $\mathrm{V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz}$ |  | 75 |  | 75 |  |
|  |  | $\mathrm{V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz}$ |  | 100 |  | 100 |  |
| $\mathrm{C}_{\text {iss }}$ | Input Capacitance | $V_{\text {DS }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 4 |  | 4 | pF |
| Coss | Output Capacitance | $V_{\text {DS }}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 2 |  | 2 | pF |
| Crss | Reverse Transfer Capacitance | $V_{D S}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 0.8 |  | 0.8 | pF |
| $\mathrm{G}_{\text {is }}$ | Input Conductance | $\begin{aligned} & V_{D S}=15 \mathrm{~V}, \mathrm{~V}_{G S}=0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz} \end{aligned}$ |  | $\begin{gathered} 100 \\ 1000 \\ \hline \end{gathered}$ |  | $\begin{gathered} 100 \\ 1000 \end{gathered}$ | $\mu \mathrm{S}$ |
| $\mathrm{b}_{\text {is }}$ | Input Susceptance | $\begin{aligned} & V_{D S}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz} \end{aligned}$ |  | $\begin{gathered} \hline 2500 \\ 10000 \\ \hline \end{gathered}$ |  | $\begin{gathered} \hline 2500 \\ 10000 \\ \hline \end{gathered}$ | $\mu \mathrm{S}$ |
| bos | Output Susceptance | $\begin{aligned} & V_{D S}=15 \mathrm{~V}, \mathrm{~V}_{G S}=0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 1000 \\ & 4000 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 1000 \\ & 4000 \\ & \hline \end{aligned}$ | $\mu \mathrm{S}$ |
| $\mathrm{G}_{\mathrm{ps}}$ | Power Gain | $\begin{aligned} & V_{D S}=15 \mathrm{~V}, \mathrm{ID}_{\mathrm{D}}=5 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=5 \mathrm{~mA}, \mathrm{f}=400 \mathrm{MHz} \end{aligned}$ | $\begin{aligned} & 18 \\ & 10 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 18 \\ & 10 \\ & \hline \end{aligned}$ |  | dB |
| NF | Noise Figure | $\begin{aligned} \mathrm{V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}} & =0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz} \\ \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}} & =0 \mathrm{~V}, \mathrm{f}=400 \mathrm{MHz} \\ \mathrm{R}_{\mathrm{G}} & =1 \mathrm{k} \Omega \end{aligned}$ |  | $\begin{aligned} & 2 \\ & 4 \end{aligned}$ |  | $\begin{aligned} & 2 \\ & 4 \end{aligned}$ | dB |

## SOT23 (TO-236AB) Mechanical and Layout Data

## Package Outline Data



1. All linear dimensions are in millimeters.
2. Package weight approximately 0.12 grams
3. Molded plastic case UL 94V-O rated
4. For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
5. Bulk product is shipped in standard ESD shipping material
6. Refer to JEDEC standards for additional information.

## Suggested Pad Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

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## T0-72 Mechanical and Layout Data

## Package Outline Data



1. All linear dimensions are in millimeters.
2. Four leaded device. Not all leads are shown in drawing views.
3. Package weight approximately 0.31 grams
4. Bulk product is shipped in standard ESD shipping material
5. Refer to JEDEC standards for additional information.

## Suggested Through-Hole Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

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## TO-92 Mechanical and Layout Data

## Package Outline Data



1. All linear dimensions are in millimeters.
2. Package weight approximately 0.19 grams
3. Molded plastic case UL 94V-0 rated
4. Bulk product is shipped in standard ESD shipping material
5. Refer to JEDEC standards for additional information.

## Suggested Through-Hole Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

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